

MC33078, MC33079

Low Noise Dual/Quad Operational Amplifiers

The MC33078/9 series is a family of high quality monolithic amplifiers employing Bipolar technology with innovative high performance concepts for quality audio and data signal processing applications. This family incorporates the use of high frequency PNP input transistors to produce amplifiers exhibiting low input voltage noise with high gain bandwidth product and slew rate. The all NPN output stage exhibits no deadband crossover distortion, large output voltage swing, excellent phase and gain margins, low open loop high frequency output impedance and symmetrical source and sink AC frequency performance.

The MC33078/9 family offers both dual and quad amplifier versions and is available in the plastic DIP and SOIC packages (P and D suffixes).

Features

- Dual Supply Operation: ± 5.0 V to ± 18 V
- Low Voltage Noise: 4.5 nV/ $\sqrt{\text{Hz}}$
- Low Input Offset Voltage: 0.15 mV
- Low T.C. of Input Offset Voltage: 2.0 $\mu\text{V}/^\circ\text{C}$
- Low Total Harmonic Distortion: 0.002%
- High Gain Bandwidth Product: 16 MHz
- High Slew Rate: 7.0 V/ μs
- High Open Loop AC Gain: 800 @ 20 kHz
- Excellent Frequency Stability
- Large Output Voltage Swing: $+14.1$ V / -14.6 V
- ESD Diodes Provided on the Inputs
- Pb-Free Packages are Available

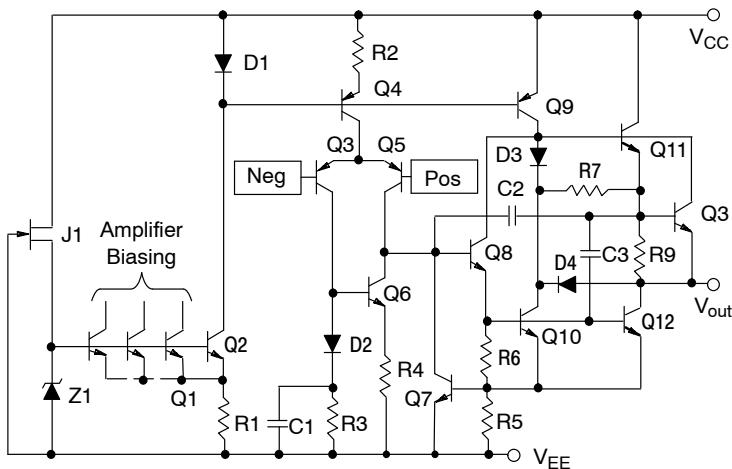


Figure 1. Representative Schematic Diagram
(Each Amplifier)

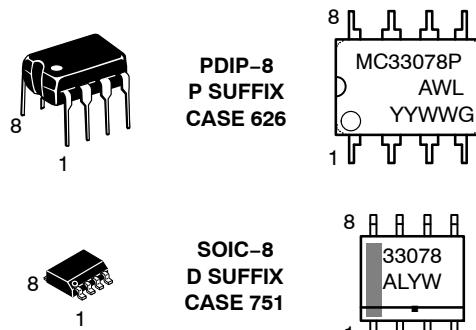


ON Semiconductor®

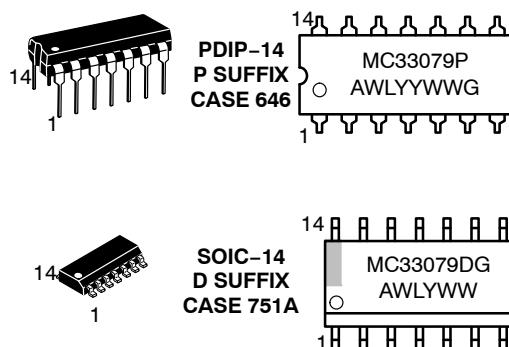
<http://onsemi.com>

MARKING DIAGRAMS

DUAL



QUAD



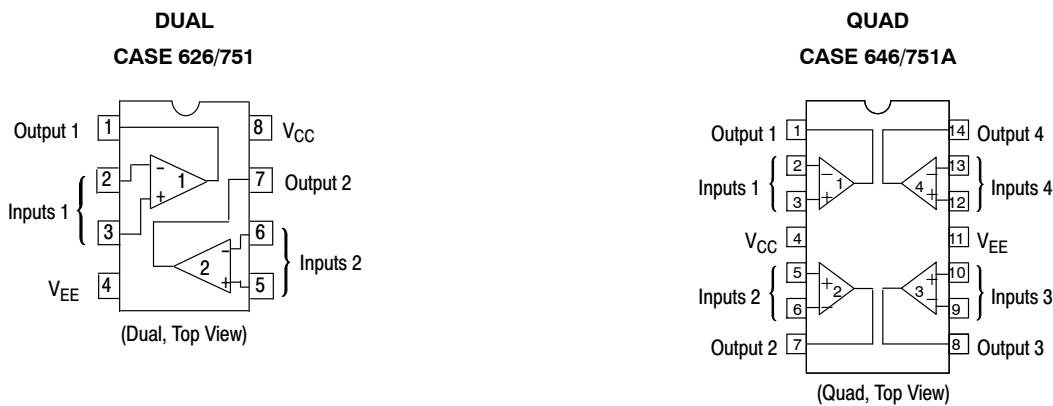
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or ▀ = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

MC33078, MC33079

PIN CONNECTIONS



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|------------------------------------------------------|------------------|--------------------------|------|
| Supply Voltage (V _{CC} to V _{EE}) | V _S | +36 | V |
| Input Differential Voltage Range | V _{IDR} | Note 1 | V |
| Input Voltage Range | V _{IR} | Note 1 | V |
| Output Short Circuit Duration (Note 2) | t _{SC} | Indefinite | sec |
| Maximum Junction Temperature | T _J | +150 | °C |
| Storage Temperature | T _{stg} | -60 to +150 | °C |
| ESD Protection at any Pin MC33078 MC33079 | V _{esd} | 600 200 550 150 | V |
| Maximum Power Dissipation | P _D | Note 2 | mW |
| Operating Temperature Range | T _A | -40 to +85 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Either or both input voltages must not exceed the magnitude of V_{CC} or V_{EE}.
2. Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded (see Figure 2).

MC33078, MC33079

DC ELECTRICAL CHARACTERISTICS ($V_{CC} = +15$ V, $V_{EE} = -15$ V, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

| Characteristics | Symbol | Min | Typ | Max | Unit |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------|------------------------------------|----------------------------------------------------|----------------------------------|------------------------------|
| Input Offset Voltage ($R_S = 10 \Omega$, $V_{CM} = 0$ V, $V_O = 0$ V) (MC33078) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ (MC33079) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ | $ V_{IO} $ | — — — — | 0.15 — 0.15 — | 2.0 3.0 2.5 3.5 | mV |
| Average Temperature Coefficient of Input Offset Voltage $R_S = 10 \Omega$, $V_{CM} = 0$ V, $V_O = 0$ V, $T_A = T_{low}$ to T_{high} | $\Delta V_{IO}/\Delta T$ | — | 2.0 | — | $\mu\text{V}/^\circ\text{C}$ |
| Input Bias Current ($V_{CM} = 0$ V, $V_O = 0$ V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ | I_{IB} | — — | 300 — | 750 800 | nA |
| Input Offset Current ($V_{CM} = 0$ V, $V_O = 0$ V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ | I_{IO} | — — | 25 — | 150 175 | nA |
| Common Mode Input Voltage Range ($\Delta V_{IO} = 5.0$ mV, $V_O = 0$ V) | V_{ICR} | ± 13 | ± 14 | — | V |
| Large Signal Voltage Gain ($V_O = \pm 10$ V, $R_L = 2.0 \text{ k}\Omega$) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ | A_{VOL} | 90 85 | 110 — | — — | dB |
| Output Voltage Swing ($V_{ID} = \pm 1.0$ V) $R_L = 600 \Omega$ $R_L = 600 \Omega$ $R_L = 2.0 \text{ k}\Omega$ $R_L = 2.0 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ | V_{O+} V_{O-} V_{O+} V_{O-} V_{O+} V_{O-} | — — +13.2 — +13.5 — | +10.7 -11.9 +13.8 -13.7 +14.1 -14.6 | — — — -13.2 — -14 | V |
| Common Mode Rejection ($V_{in} = \pm 13$ V) | CMR | 80 | 100 | — | dB |
| Power Supply Rejection (Note 3) $V_{CC}/V_{EE} = +15$ V/ -15 V to +5.0 V/ -5.0 V | PSR | 80 | 105 | — | dB |
| Output Short Circuit Current ($V_{ID} = 1.0$ V, Output to Ground) Source Sink | I_{SC} | +15 -20 | +29 -37 | — — | mA |
| Power Supply Current ($V_O = 0$ V, All Amplifiers) (MC33078) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ (MC33079) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+85^\circ\text{C}$ | I_D | — — — — | 4.1 — 8.4 — | 5.0 5.5 10 11 | mA |

3. Measured with V_{CC} and V_{EE} differentially varied simultaneously.

MC33078, MC33079

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = +15$ V, $V_{EE} = -15$ V, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

| Characteristics | Symbol | Min | Typ | Max | Unit |
|--------------------------------------------------------------------------------------------------------------------------------|-----------------|--------|-------------|-----|------------------------|
| Slew Rate ($V_{in} = -10$ V to $+10$ V, $R_L = 2.0$ k Ω , $C_L = 100$ pF $A_V = +1.0$) | SR | 5.0 | 7.0 | — | V/ μ s |
| Gain Bandwidth Product ($f = 100$ kHz) | GBW | 10 | 16 | — | MHz |
| Unity Gain Bandwidth (Open Loop) | BW | — | 9.0 | — | MHz |
| Gain Margin ($R_L = 2.0$ k Ω) $C_L = 0$ pF $C_L = 100$ pF | A_m | — — | -11 -6.0 | — | dB |
| Phase Margin ($R_L = 2.0$ k Ω) $C_L = 0$ pF $C_L = 100$ pF | ϕ_m | — — | 55 40 | — | Deg |
| Channel Separation ($f = 20$ Hz to 20 kHz) | CS | — | -120 | — | dB |
| Power Bandwidth ($V_O = 27$ V _{pp} , $R_L = 2.0$ k Ω , THD $\pm 1.0\%$) | BW _p | — | 120 | — | kHz |
| Total Harmonic Distortion ($R_L = 2.0$ k Ω , $f = 20$ Hz to 20 kHz, $V_O = 3.0$ V _{rms} , $A_V = +1.0$) | THD | — | 0.002 | — | % |
| Open Loop Output Impedance ($V_O = 0$ V, $f = 9.0$ MHz) | Z _O | — | 37 | — | Ω |
| Differential Input Resistance ($V_{CM} = 0$ V) | R _{in} | — | 175 | — | k Ω |
| Differential Input Capacitance ($V_{CM} = 0$ V) | C _{in} | — | 12 | — | pF |
| Equivalent Input Noise Voltage ($R_S = 100$ Ω , $f = 1.0$ kHz) | e _n | — | 4.5 | — | nV/ $\sqrt{\text{Hz}}$ |
| Equivalent Input Noise Current ($f = 1.0$ kHz) | i _n | — | 0.5 | — | Hz $\sqrt{\text{pA}}$ |

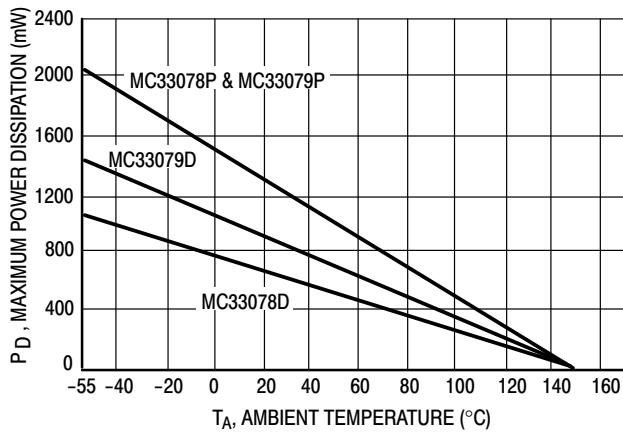


Figure 2. Maximum Power Dissipation versus Temperature

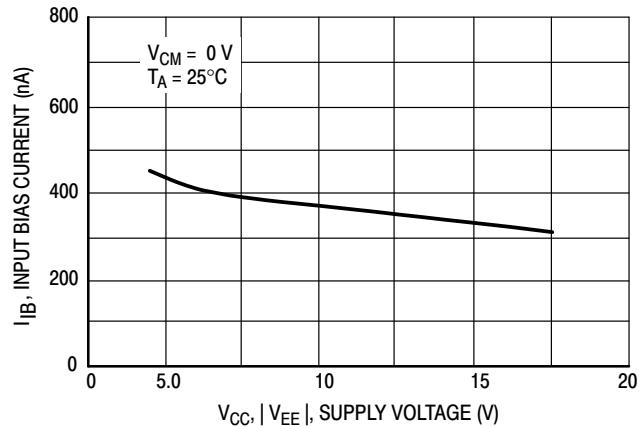


Figure 3. Input Bias Current versus Supply Voltage

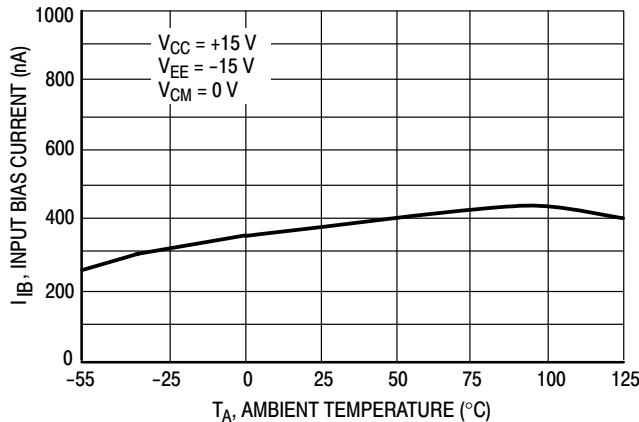


Figure 4. Input Bias Current versus Temperature

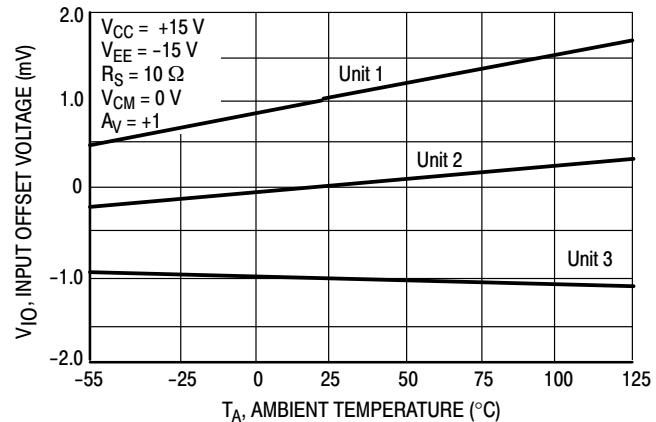
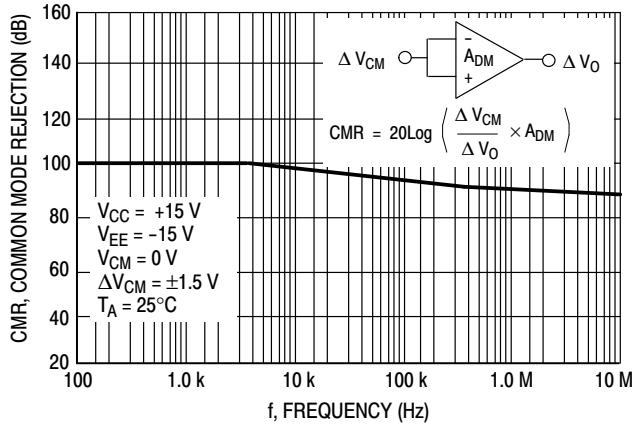
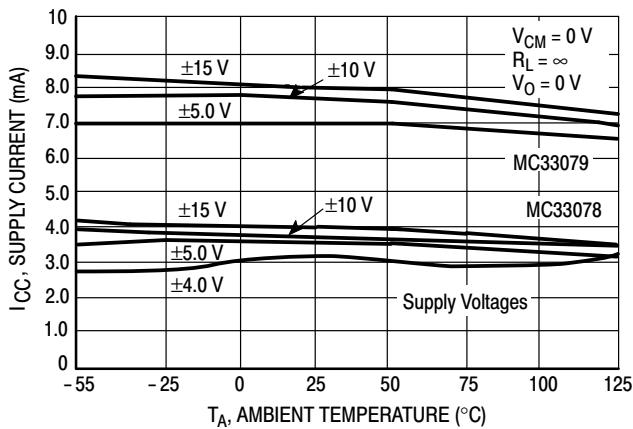
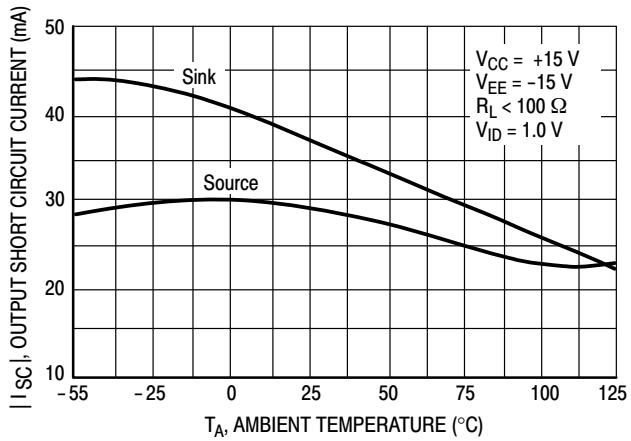
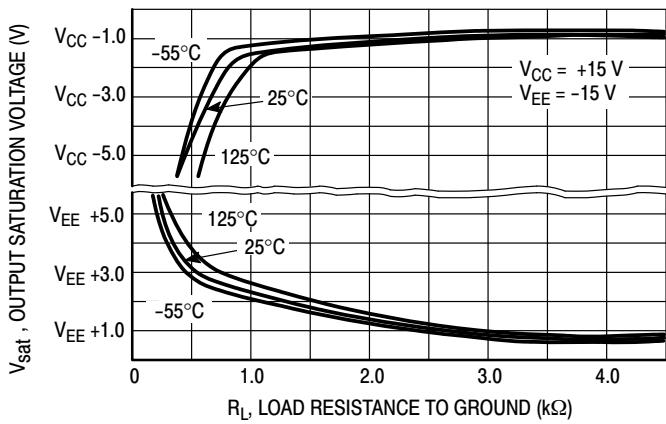
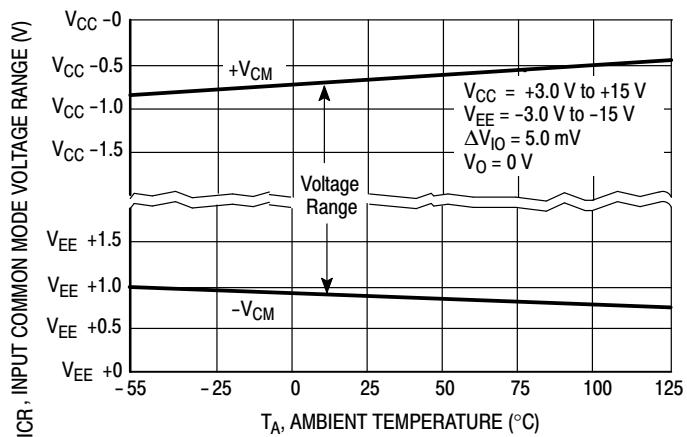
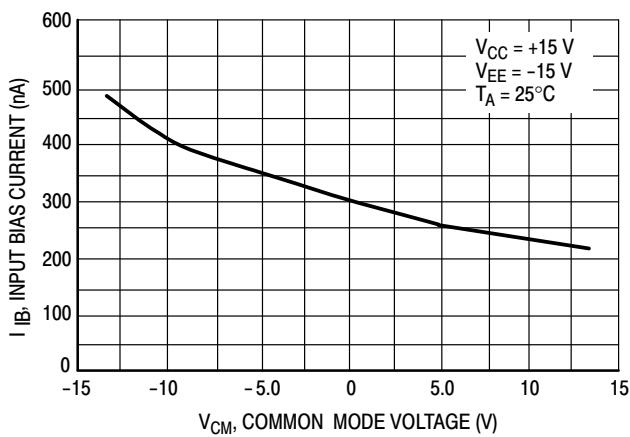


Figure 5. Input Offset Voltage versus Temperature

MC33078, MC33079



MC33078, MC33079

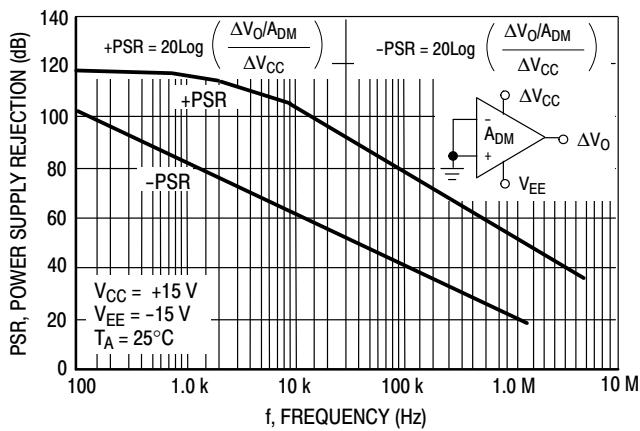


Figure 12. Power Supply Rejection versus Frequency

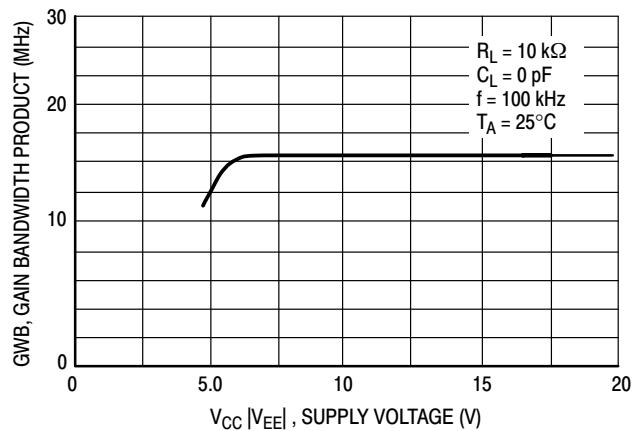


Figure 13. Gain Bandwidth Product versus Supply Voltage

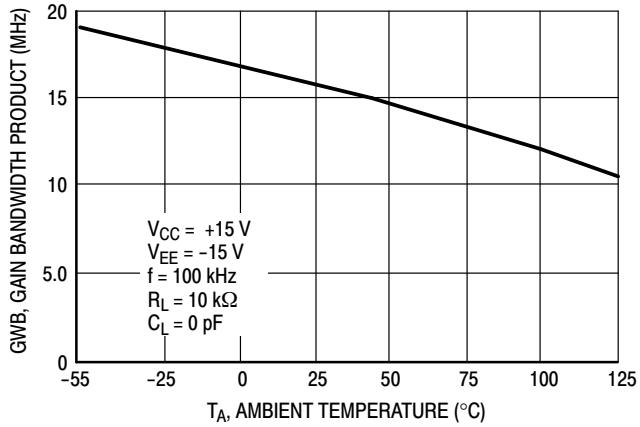


Figure 14. Gain Bandwidth Product versus Temperature

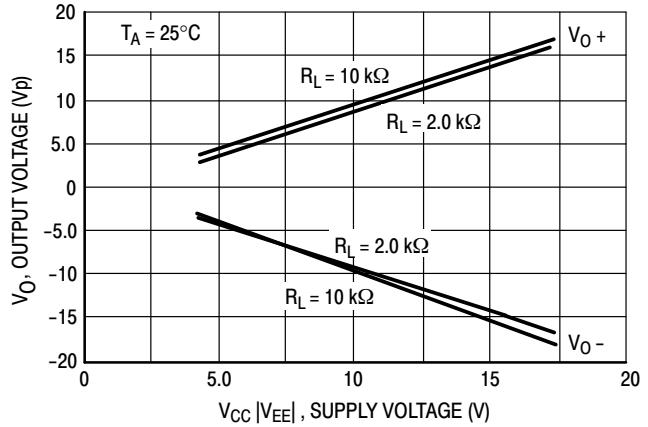


Figure 15. Maximum Output Voltage versus Supply Voltage

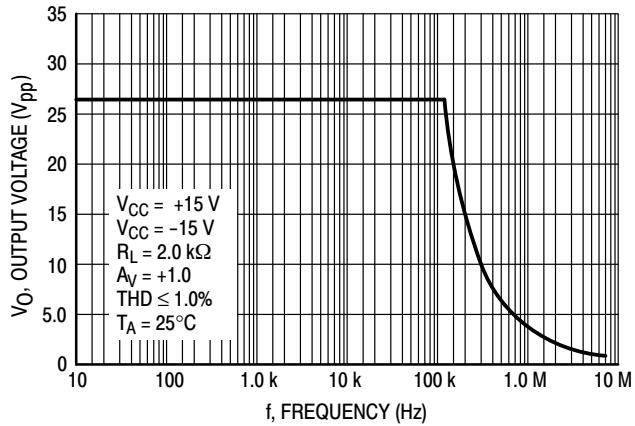


Figure 16. Output Voltage versus Frequency

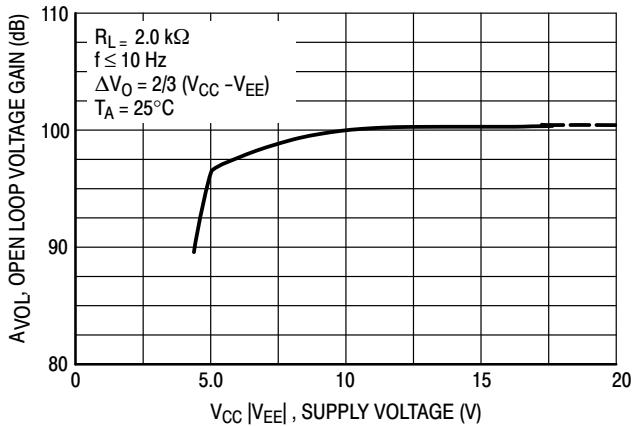


Figure 17. Open Loop Voltage Gain versus Supply Voltage

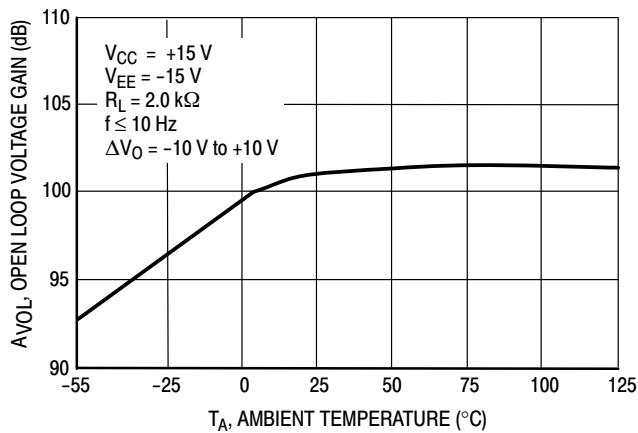


Figure 18. Open Loop Voltage Gain versus Temperature

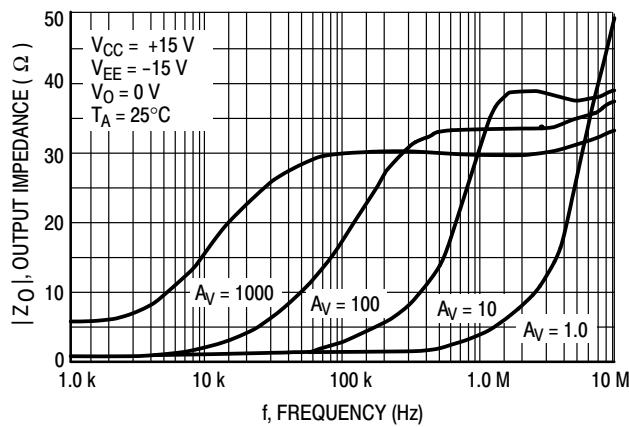


Figure 19. Output Impedance versus Frequency

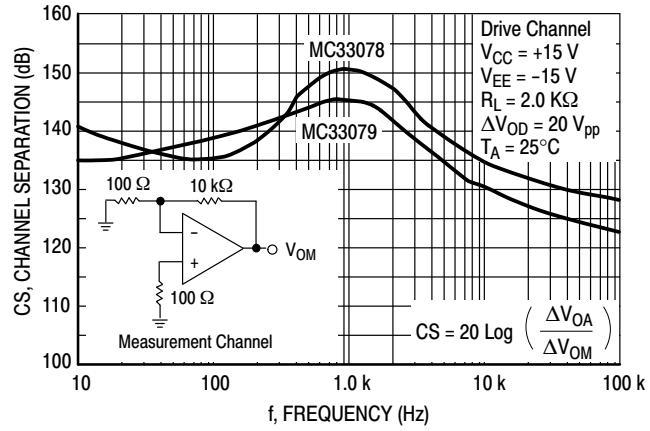


Figure 20. Channel Separation versus Frequency

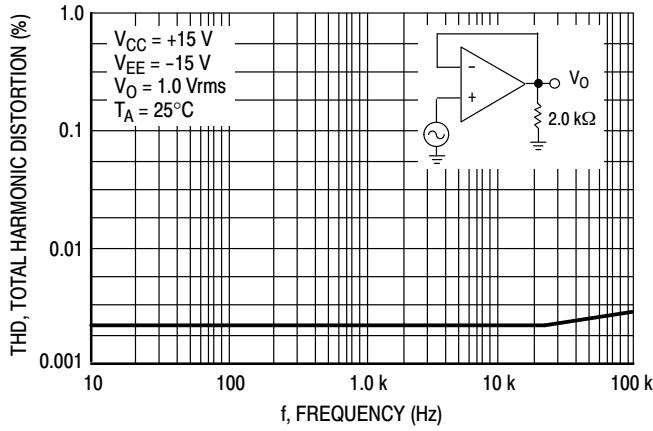


Figure 21. Total Harmonic Distortion versus Frequency

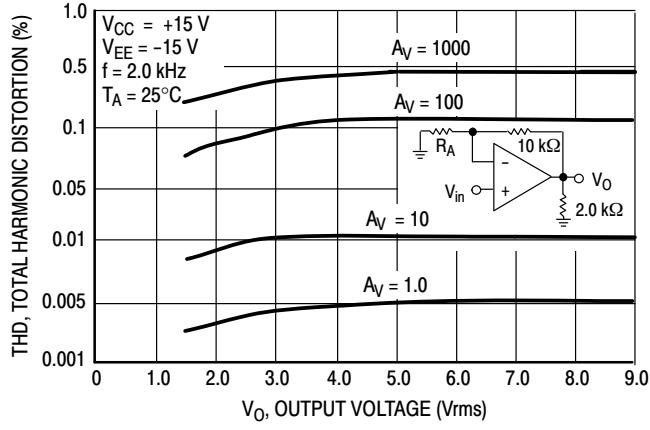


Figure 22. Total Harmonic Distortion versus Output Voltage

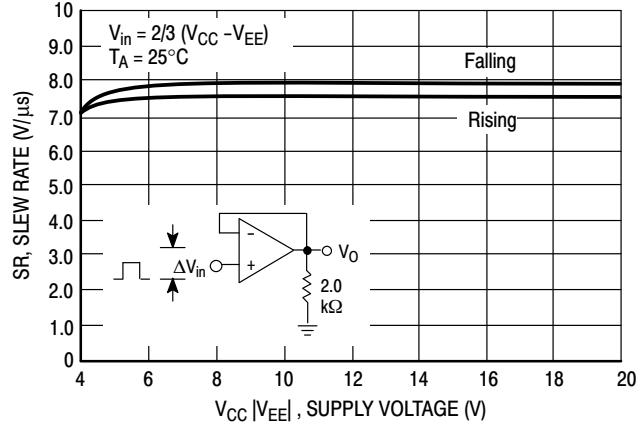
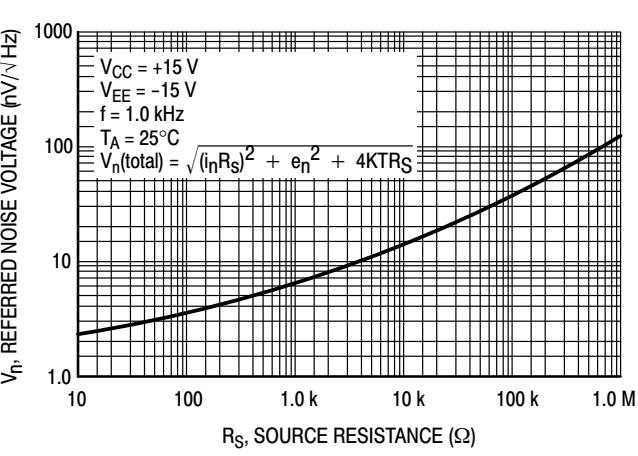
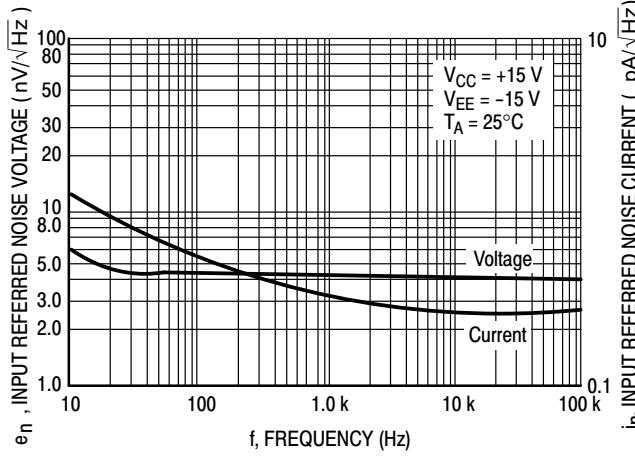
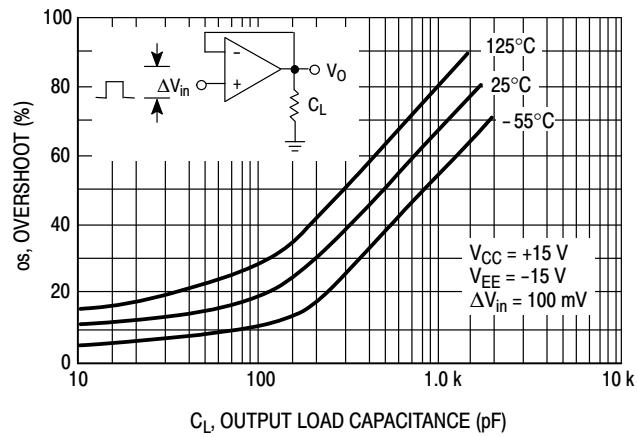
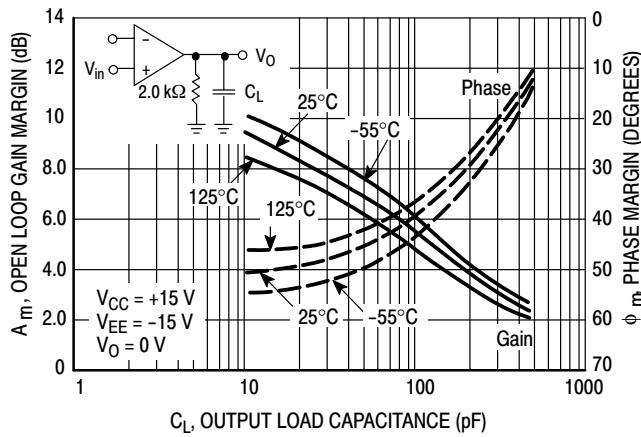
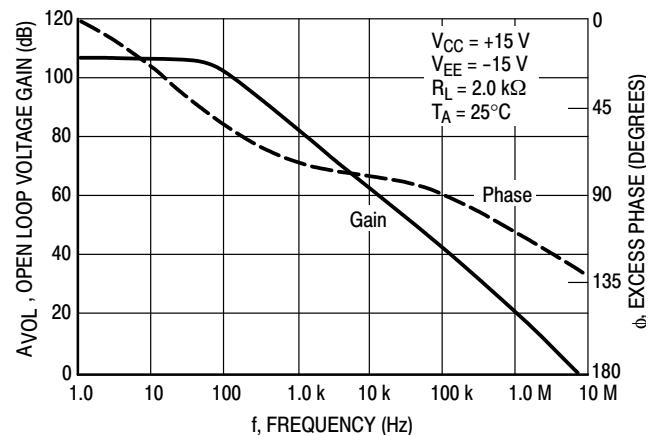
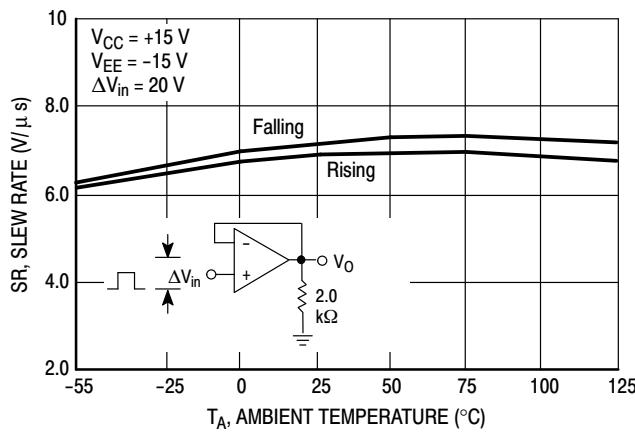


Figure 23. Slew Rate versus Supply Voltage

MC33078, MC33079



MC33078, MC33079

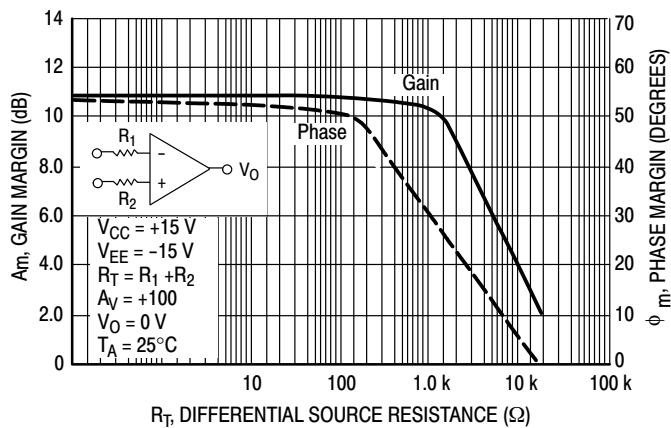


Figure 30. Phase Margin and Gain Margin versus Differential Source Resistance

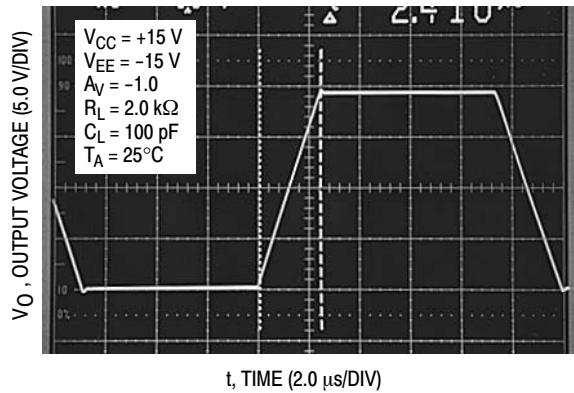


Figure 31. Inverting Amplifier Slew Rate

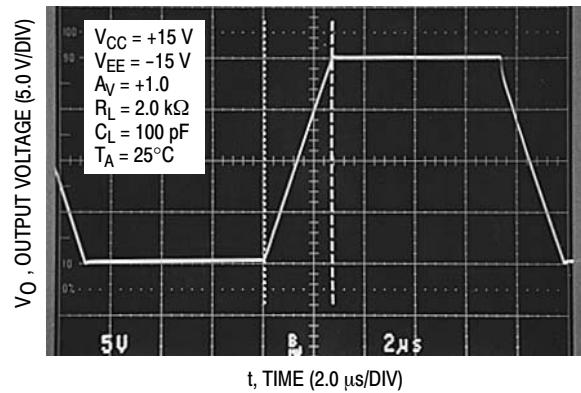


Figure 32. Non-inverting Amplifier Slew Rate

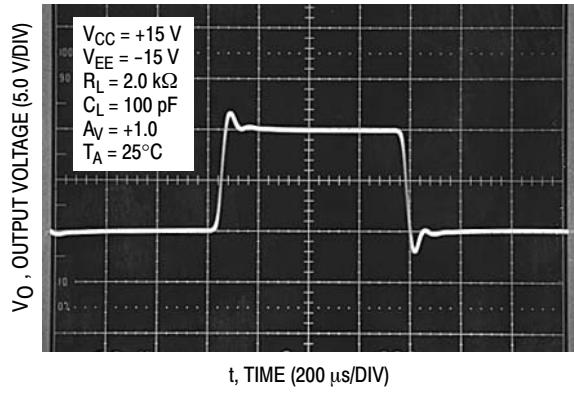


Figure 33. Non-inverting Amplifier Overshoot

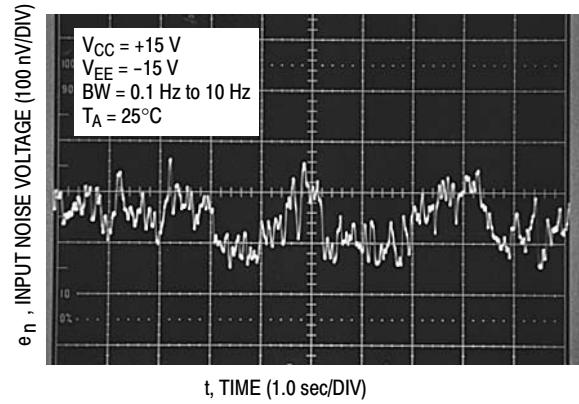
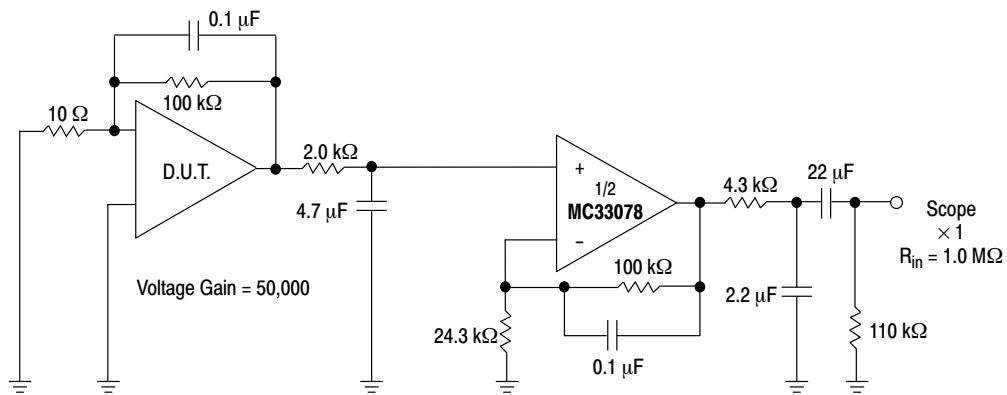


Figure 34. Low Frequency Noise Voltage versus Time



Note: All capacitors are non-polarized.

**Figure 35. Voltage Noise Test Circuit
(0.1 Hz to 10 Hz_{p-p})**

ORDERING INFORMATION

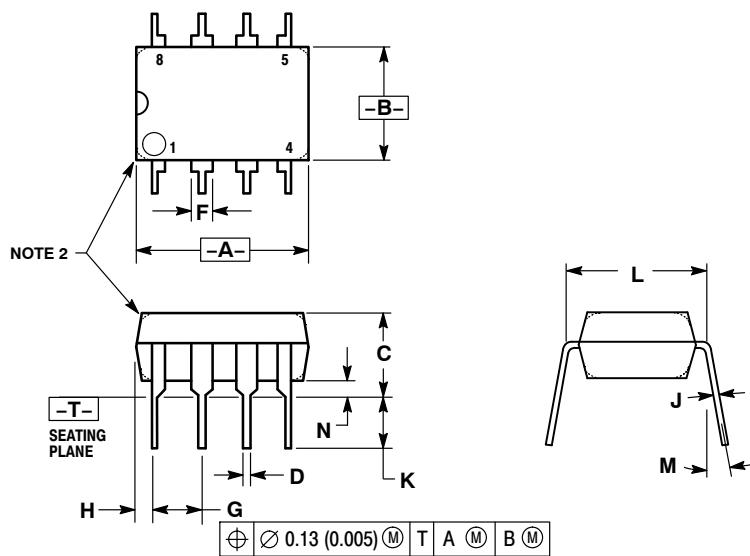
| Device | Package | Shipping [†] |
|-------------|----------------------|-----------------------|
| MC33078D | SOIC-8 | 98 Units / Rail |
| MC33078DG | SOIC-8 (Pb-Free) | |
| MC33078DR2 | SOIC-8 | 2500 / Tape & Reel |
| MC33078DR2G | SOIC-8 (Pb-Free) | |
| MC33078P | PDIP-8 | 50 Units / Rail |
| MC33078PG | PDIP-8 (Pb-Free) | |
| MC33079D | SOIC-14 | 55 Units / Rail |
| MC33079DG | SOIC-14 (Pb-Free) | |
| MC33079DR2 | SOIC-14 | 2500 / Tape & Reel |
| MC33079DR2G | SOIC-14 (Pb-Free) | |
| MC33079P | PDIP-14 | 25 Units / Rail |
| MC33079PG | PDIP-14 (Pb-Free) | |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC33078, MC33079

PACKAGE DIMENSIONS

**PDIP-8
P SUFFIX
CASE 626-05
ISSUE L**



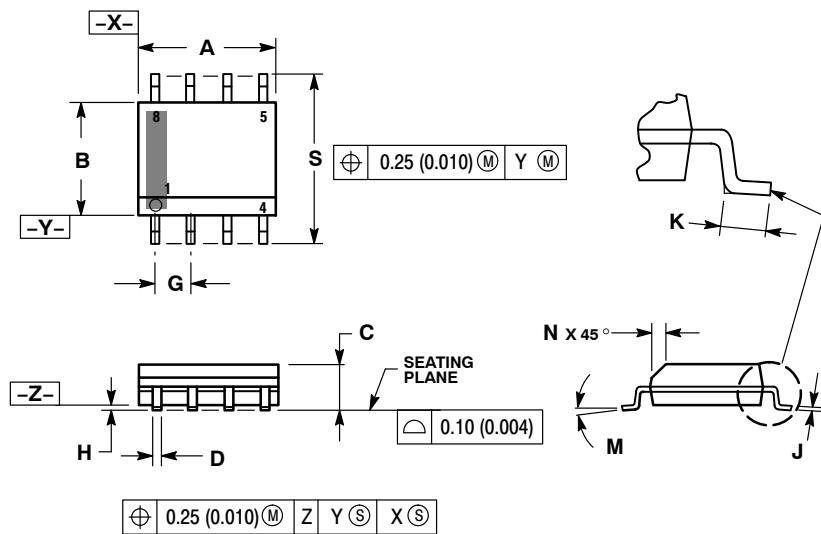
- NOTES:
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------------|-----------|------------|
| | MIN | MAX | MIN | MAX |
| A | 9.40 | 10.16 | 0.370 | 0.400 |
| B | 6.10 | 6.60 | 0.240 | 0.260 |
| C | 3.94 | 4.45 | 0.155 | 0.175 |
| D | 0.38 | 0.51 | 0.015 | 0.020 |
| F | 1.02 | 1.78 | 0.040 | 0.070 |
| G | 2.54 BSC | | 0.100 BSC | |
| H | 0.76 | 1.27 | 0.030 | 0.050 |
| J | 0.20 | 0.30 | 0.008 | 0.012 |
| K | 2.92 | 3.43 | 0.115 | 0.135 |
| L | 7.62 BSC | | 0.300 BSC | |
| M | --- | 10° | --- | 10° |
| N | 0.76 | 1.01 | 0.030 | 0.040 |

MC33078, MC33079

PACKAGE DIMENSIONS

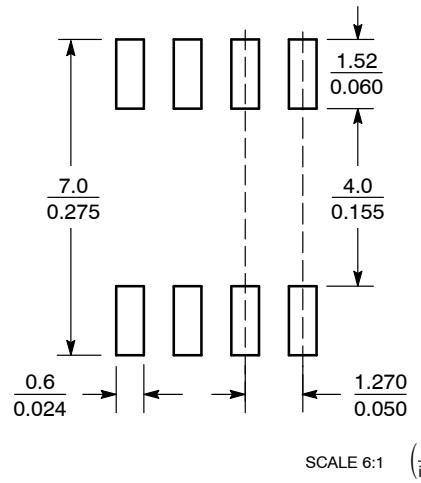
SOIC-8 NB CASE 751-07 ISSUE AH



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 4.80 | 5.00 | 0.189 | 0.197 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.053 | 0.069 |
| D | 0.33 | 0.51 | 0.013 | 0.020 |
| G | 1.27 BSC | | 0.050 BSC | |
| H | 0.10 | 0.25 | 0.004 | 0.010 |
| J | 0.19 | 0.25 | 0.007 | 0.010 |
| K | 0.40 | 1.27 | 0.016 | 0.050 |
| M | 0 ° | 8 ° | 0 ° | 8 ° |
| N | 0.25 | 0.50 | 0.010 | 0.020 |
| S | 5.80 | 6.20 | 0.228 | 0.244 |

SOLDERING FOOTPRINT*

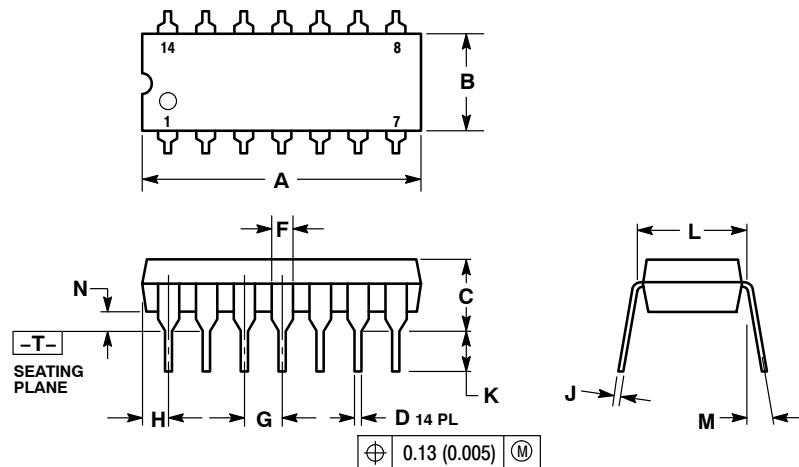


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MC33078, MC33079

PACKAGE DIMENSIONS

PDIP-14
CASE 646-06
ISSUE P



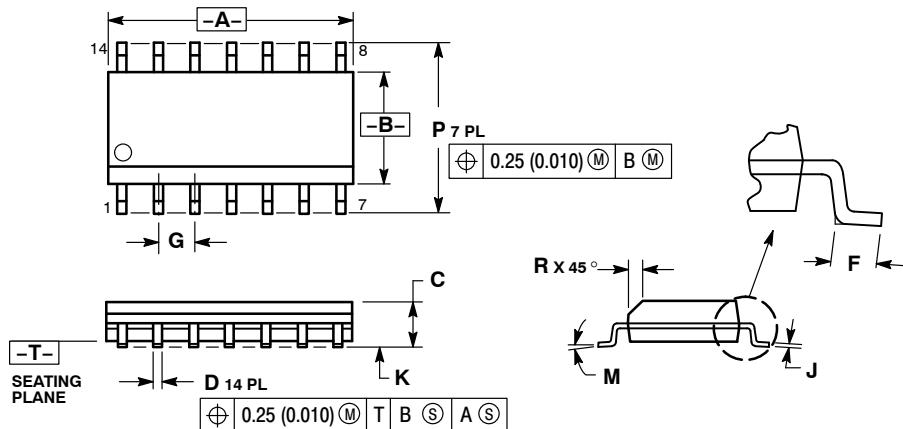
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.715 | 0.770 | 18.16 | 19.56 |
| B | 0.240 | 0.260 | 6.10 | 6.60 |
| C | 0.145 | 0.185 | 3.69 | 4.69 |
| D | 0.015 | 0.021 | 0.38 | 0.53 |
| F | 0.040 | 0.070 | 1.02 | 1.78 |
| G | 0.100 | 0.120 | 2.54 | 3.12 |
| H | 0.052 | 0.095 | 1.32 | 2.41 |
| J | 0.008 | 0.015 | 0.20 | 0.38 |
| K | 0.115 | 0.135 | 2.92 | 3.43 |
| L | 0.290 | 0.310 | 7.37 | 7.87 |
| M | --- | 10° | --- | 10° |
| N | 0.015 | 0.039 | 0.38 | 1.01 |

MC33078, MC33079

SOIC-14 CASE 751A-03 ISSUE H

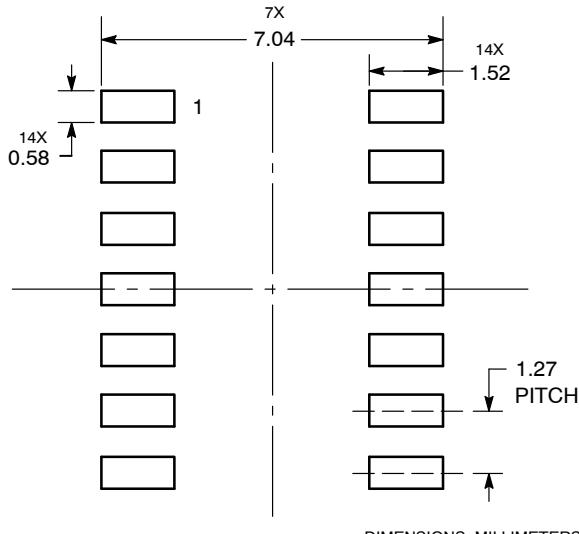


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 8.55 | 8.75 | 0.337 | 0.344 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| E | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 | BSC | 0.050 | BSC |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0 ° | 7 ° | 0 ° | 7 ° |
| P | 5.80 | 6.20 | 0.228 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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